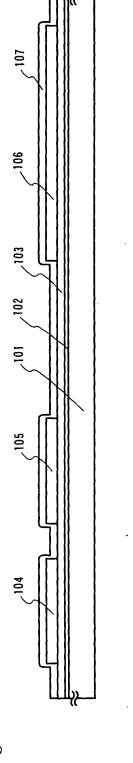
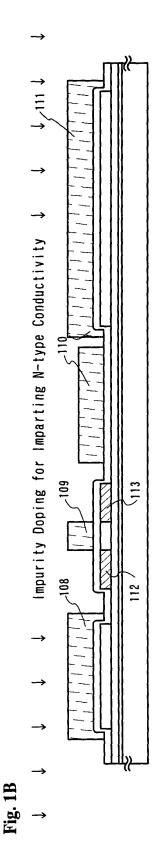
Fig. 1A





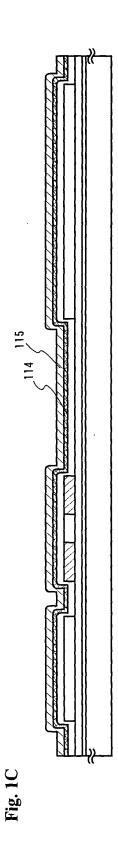
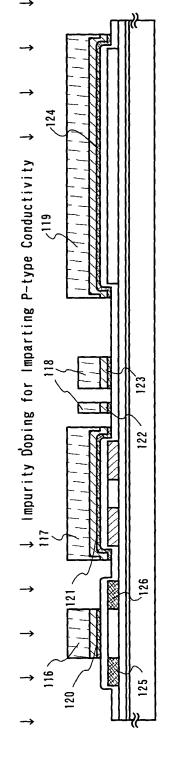
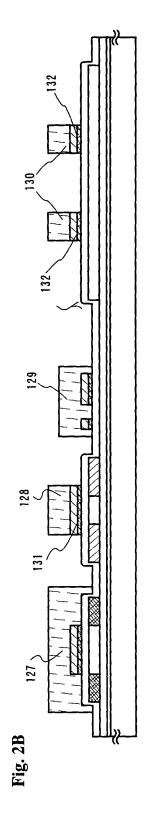


Fig. 2A





↓ Impurity Doping for Imparting N-type Conductivity ↓

Fig. 2C

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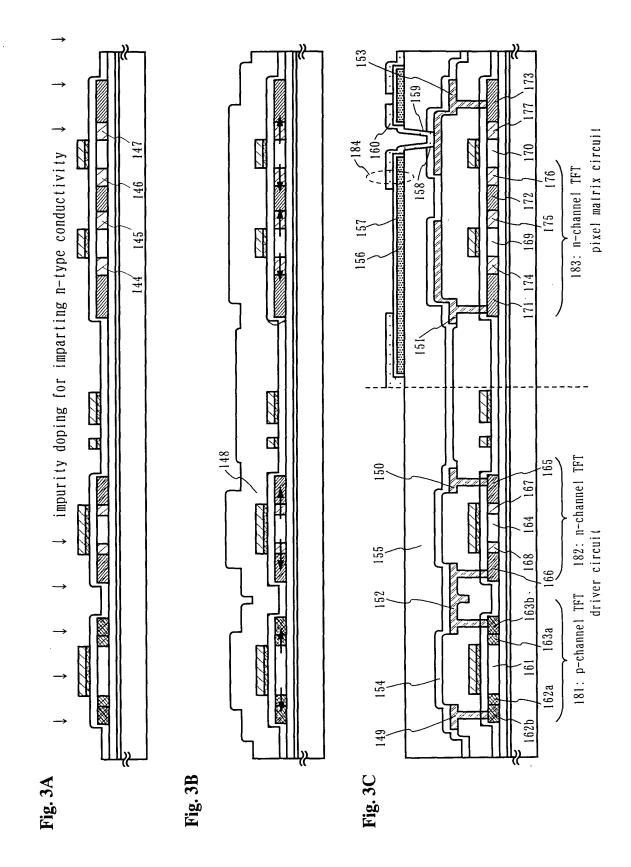


Fig. 4

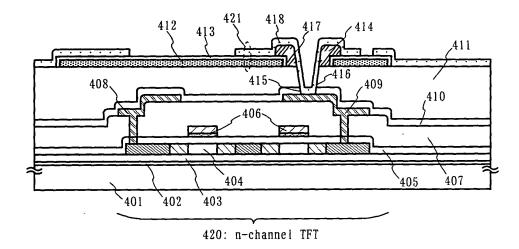
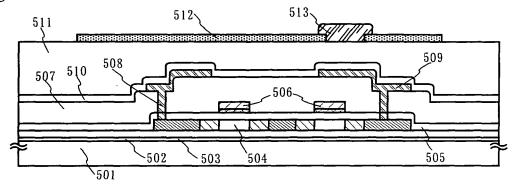
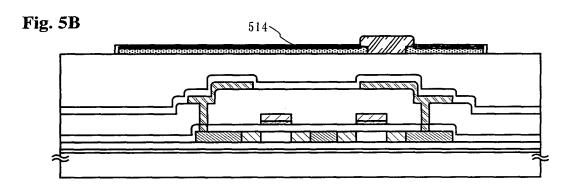
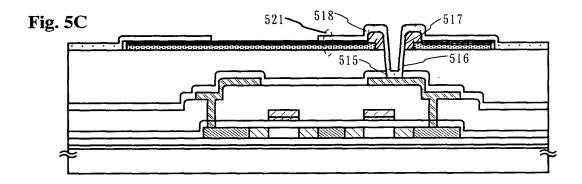
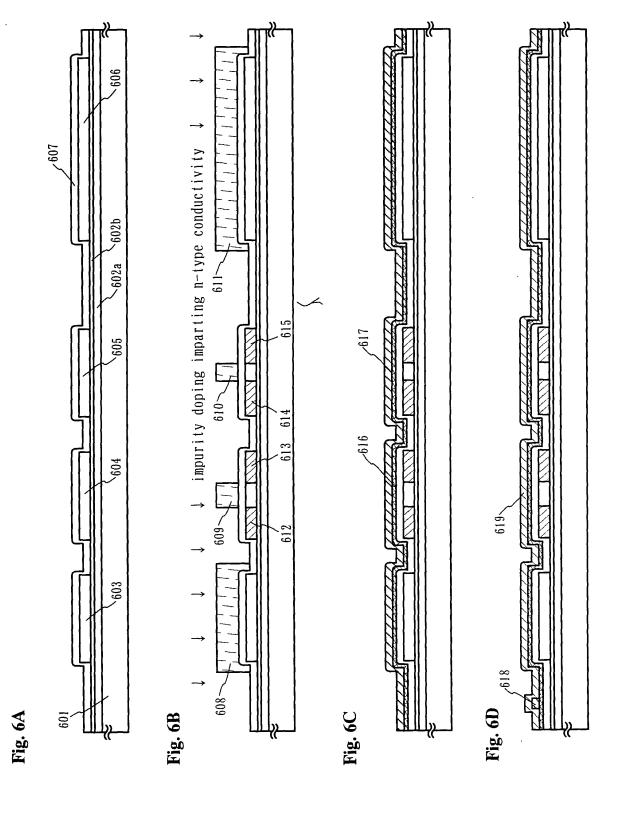


Fig. 5A









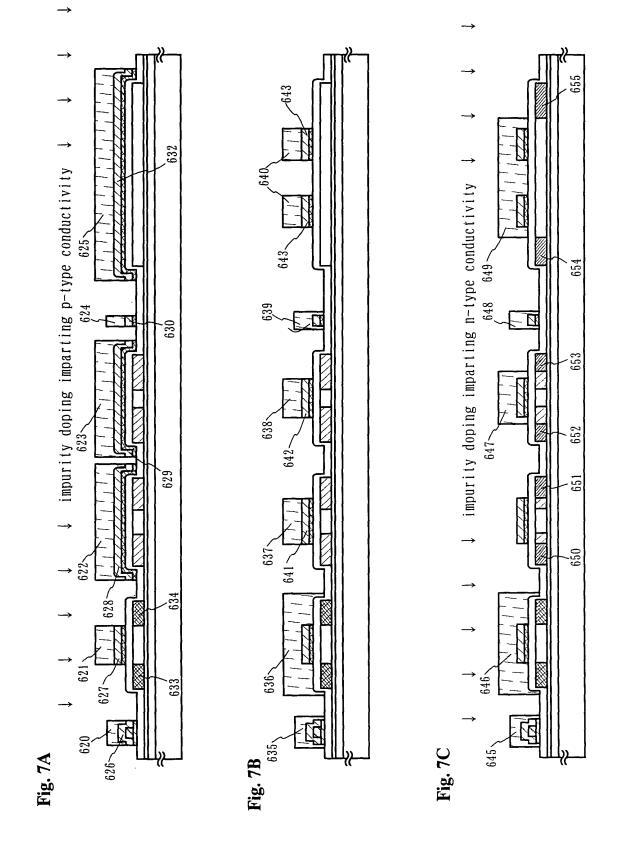
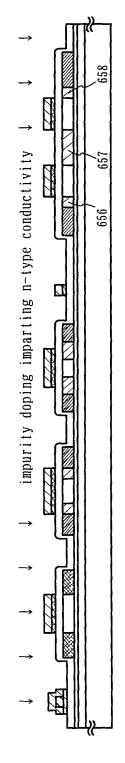
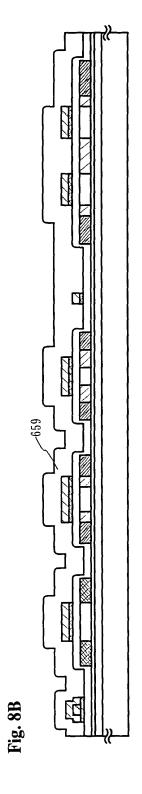
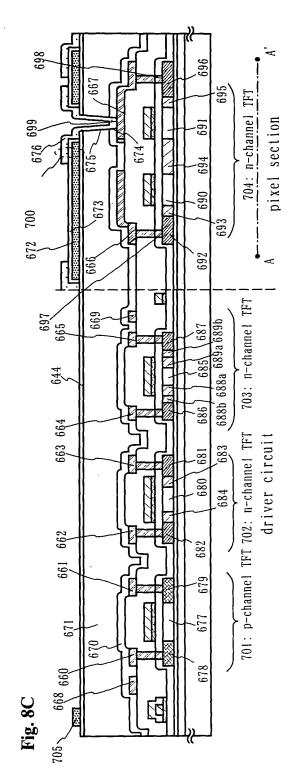
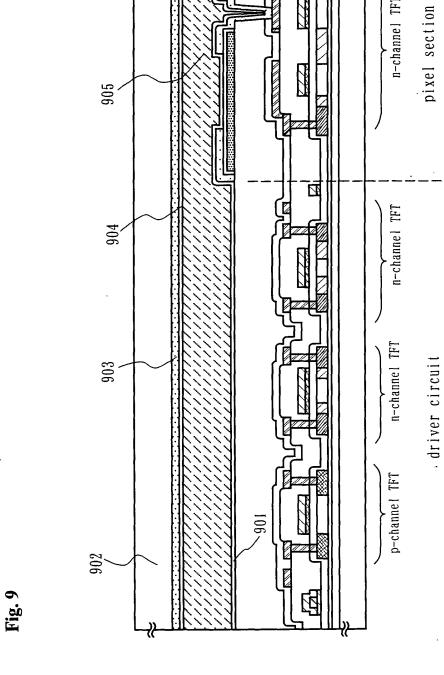


Fig. 8A









n-channel TFT

Fig. 10

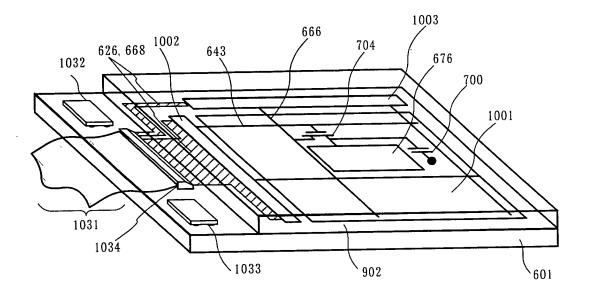
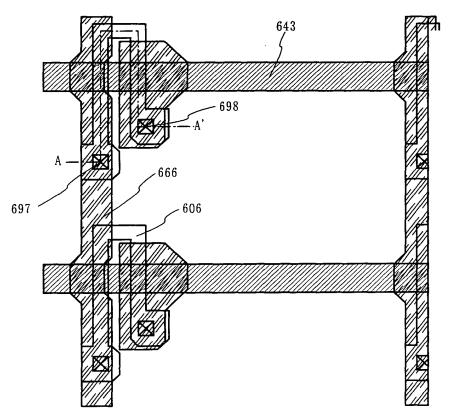


Fig. 11A



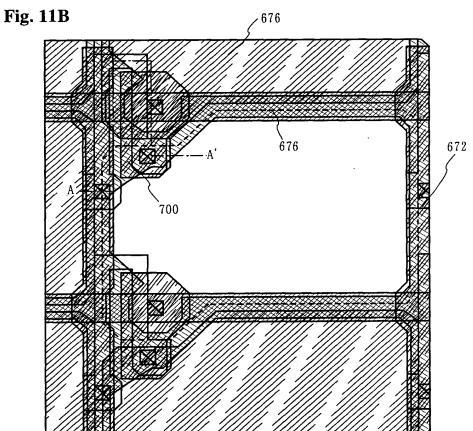


Fig. 12A

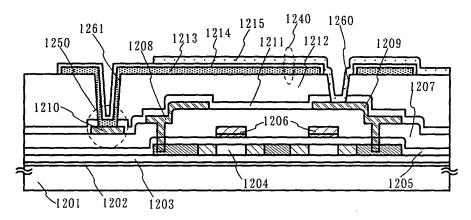


Fig. 12B

Fig. 12C

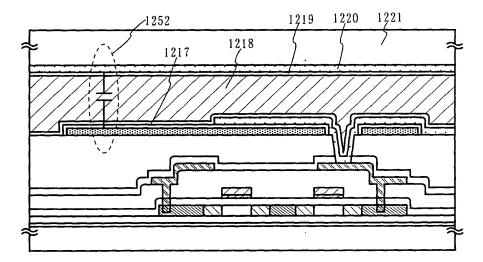


Fig. 13

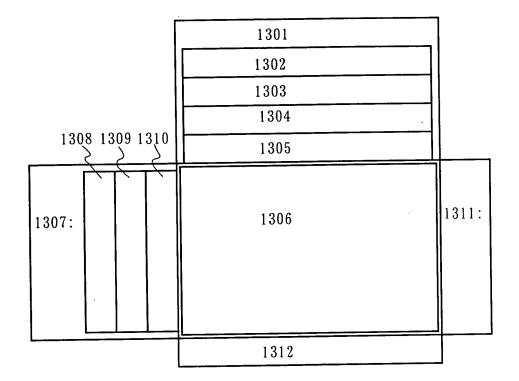


Fig. 14A

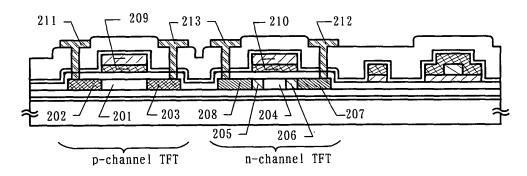


Fig. 14B

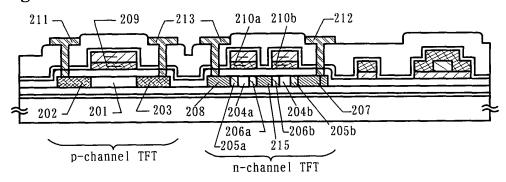


Fig. 14C

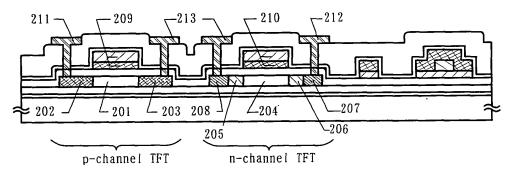


Fig. 14D

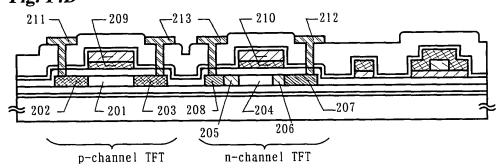
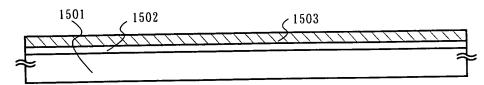


Fig. 15A



Fig, 15B

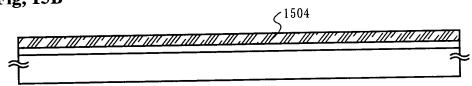


Fig. 15C

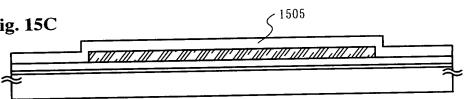


Fig. 16A

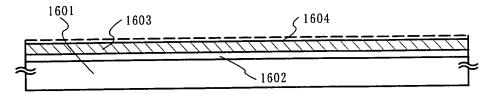


Fig. 16B

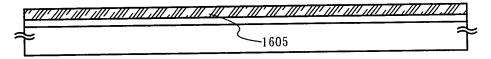


Fig. 16C

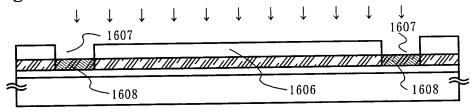


Fig. 16D

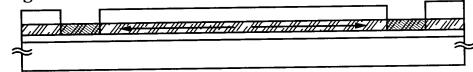


Fig. 16E

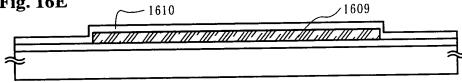
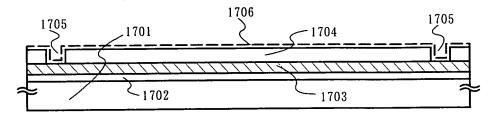
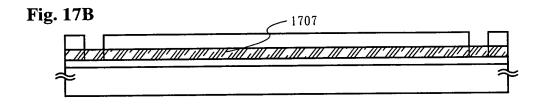


Fig. 17A





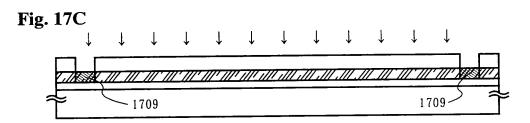
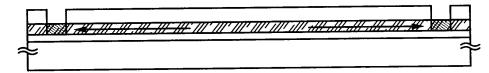


Fig. 17D



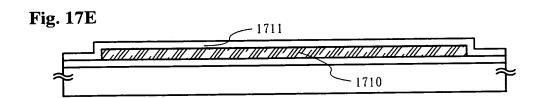


Fig. 18B Fig. 18A Ø∏D Fig. 18D Fig. 18C Fig. 18F Fig. 18E

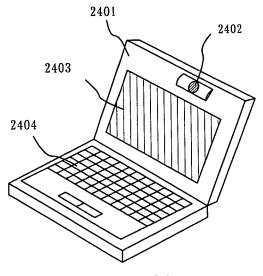


Fig. 19A

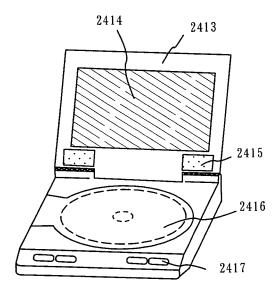


Fig. 19B

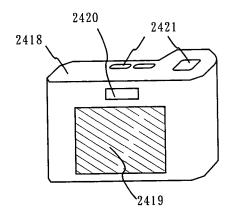
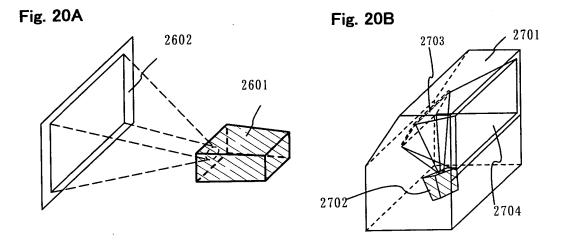
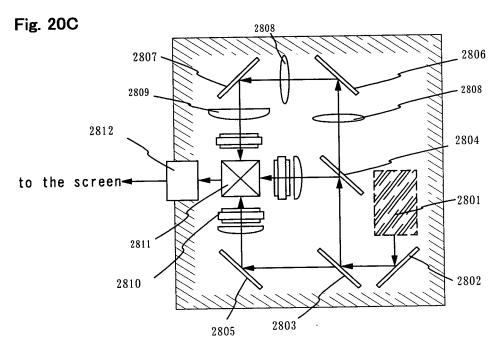


Fig. 19C





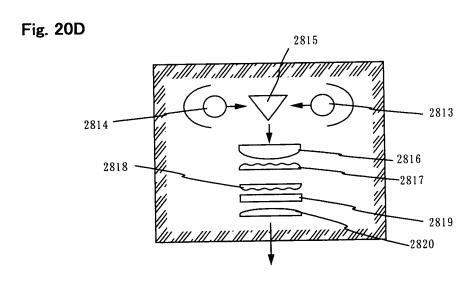


Fig. 21A

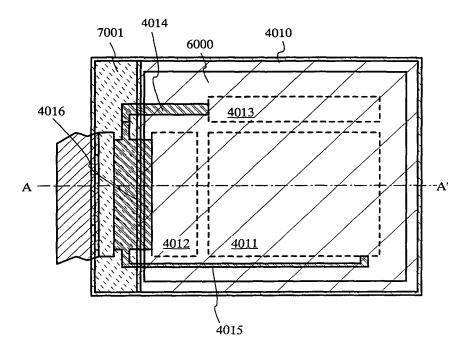


Fig. 21B

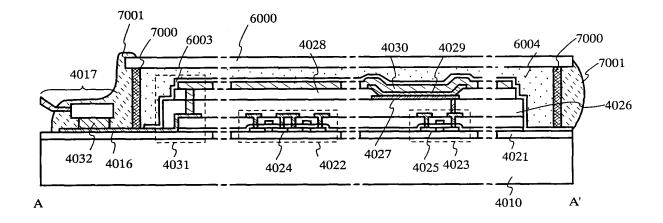


Fig. 22A

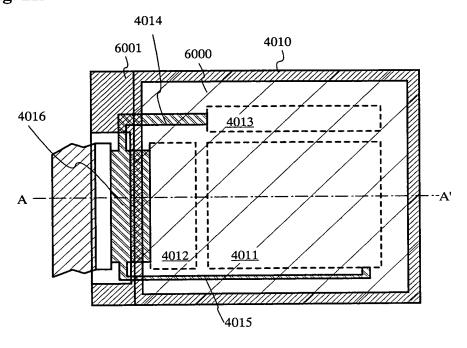


Fig. 22B

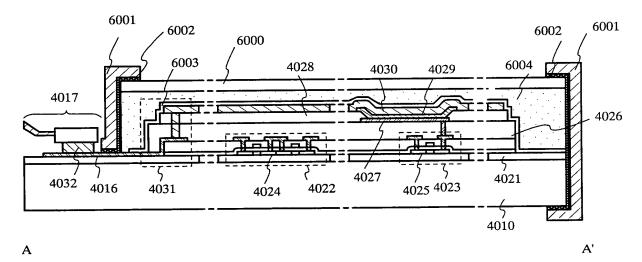


Fig. 23

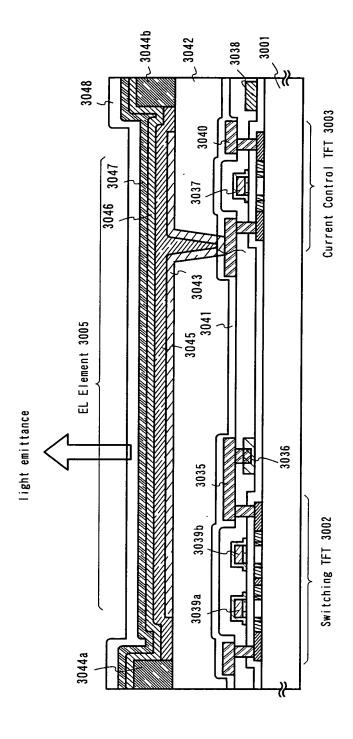


Fig. 24A

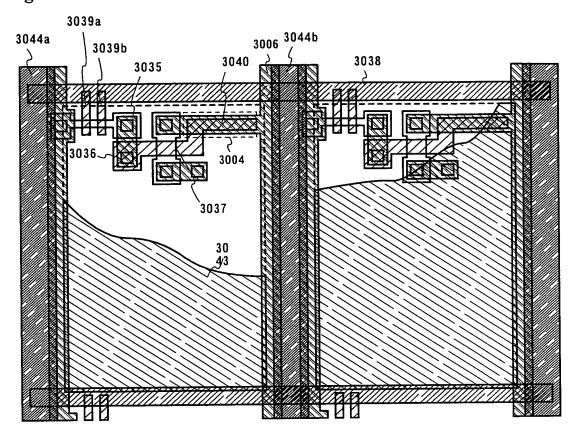


Fig. 24B

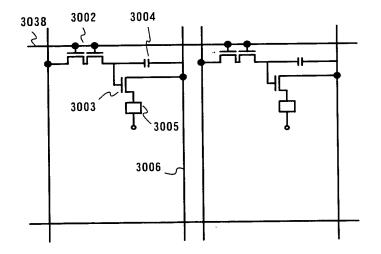


Fig. 25

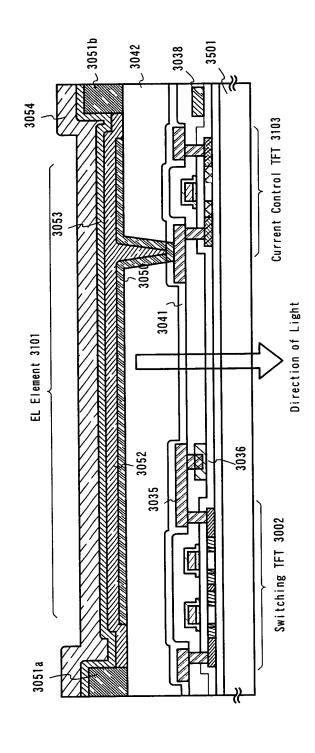


Fig. 26A

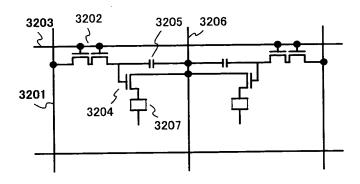
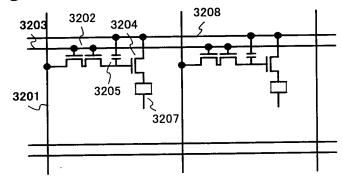


Fig. 26B



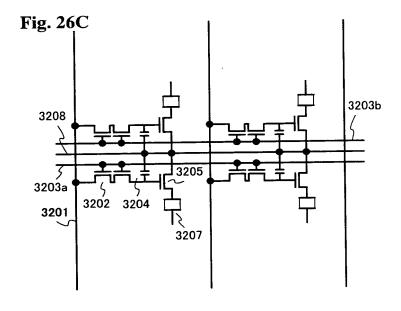
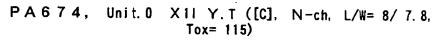
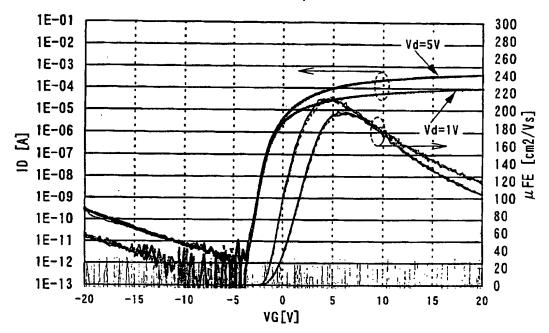
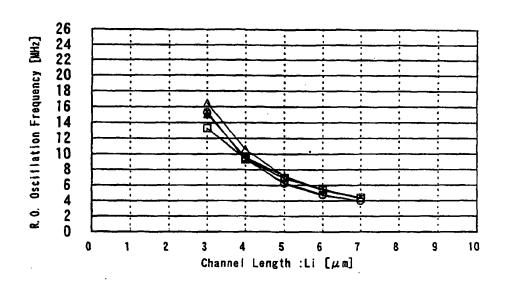


Fig. 27

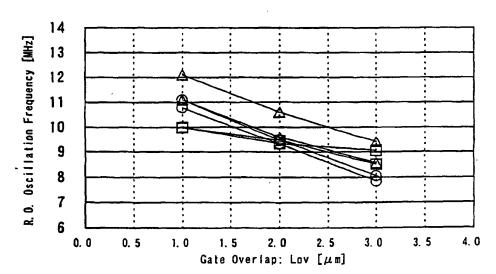






Ring Oscillator (R.O.) 19 stages, Lov=2 μ m, Loff=0 μ m, W=10 μ m \bigcirc : laser activation + heat treatment 450°C, 4 hours \bigcirc : 500°C, 4 hours \triangle : 550°C, 4 hours

Fig. 28B



Ring Oscillator (R.O.) 19 stages, Li=6 μ m, Loff=0 μ m, W=10 μ m \odot : laser activation + heat treatment 450°C, 4 hours

☐: 500°C. 4 hours△: 550°C. 4 hours